

SANYO Semiconductors

DATA SHEET

An ON Semiconductor Company

LV5762LF—

Bi-CMOS IC

Step-down Switching Regulator

Overview

LV5762LF is a 1ch step-down voltage switching regulator.

Functions

- 1ch step-down switching regulator controller
- Load-independent soft start circuit

• Frequency fold back function

- ON/OFF function
- Built-in pulse-by-pulse OCP circuit. It is detected by using ON resistance of an external MOS.

Specifications

Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage	V _{IN} max		45	٧
Allowable power dissipation	Pd max	*)	0.65	W
Operating temperature	Topr		-40 to 85	°C
Storage temperature	Tstg		-55 to 150	°C

^{*} Specified board: 24.0mm \times 15.0mm \times 1.6mm, glass epoxy board (2-layer).

Recommended Operating Conditions at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage range 1	V _{IN}		8 to 42	V
Error amplifier input coltage	V _{FB}		0 to 1.6	V

Electrical Characteristics at Ta = 25°C, $V_{IN} = 12V$

Parameter	Symbol Conditions	Conditions	Ratings			11:4
		min	typ	max	Unit	
Reference voltage block						
Internal reference voltage Vref		Including offset of E/A	0.695	0.705	0.715	V
5V power supply V _{DD}		I _{OUT} =0 to 5mA	4.7	5.2	5.7	V

Continued on next page.

- Any and all SANYO Semiconductor Co.,Ltd. products described or contained herein are, with regard to "standard application", intended for the use as general electronics equipment (home appliances, AV equipment, communication device, office equipment, industrial equipment etc.). The products mentioned herein shall not be intended for use for any "special application" (medical equipment whose purpose is to sustain life, aerospace instrument, nuclear control device, burning appliances, transportation machine, traffic signal system, safety equipment etc.) that shall require extremely high level of reliability and can directly threaten human lives in case of failure or malfunction of the product or may cause harm to human bodies, nor shall they grant any guarantee thereof. If you should intend to use our products for applications outside the standard applications of our customer who is considering such use and/or outside the scope of our intended standard applications, please consult with us prior to the intended use. If there is no consultation or inquiry before the intended use, our customer shall be solely responsible for the use.
- Specifications of any and all SANYO Semiconductor Co.,Ltd. products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.

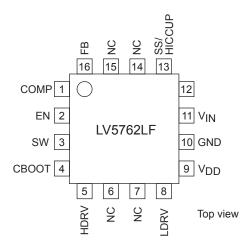
SANYO Semiconductor Co., Ltd.

LV5762LF

Continued from preceding page.

Parameter	Symbol	Conditions	Ratings			Unit
Faianielei			min	typ	max	Unit
Triangular waveform oscillator block						
Oscillation frequency	fosc		870	1000	1130	kHz
Frequency variation	fosc_DV	V _{IN} =8 to 42V		1		%
Oscillatory frequency fold back detection voltage	V _{OSC} _FB	Detect IN voltage after the end of SS		0.5		V
Oscillatory frequency after fold back	fosc_FB		100	150	200	kHz
ON/OFF circuit block						
IC start-up voltage	V _{EN} _on	V _{IN} =8 to 42V		3.4	4.3	V
IC off voltage	V _{EN} _off	V _{IN} =8 to 42V	1.1	1.3		V
Soft start circuit block						
Soft start source current	I _{SS} _SC	EN > 5V, SS=0V	3.4	4.3	5.2	μΑ
Soft start sink current	I _{SS} _SK	EN > 1V, V _{DD} =5V, SS=1V		2		mA
Voltage to end the soft start function	V _{SS} _END		0.7	0.9	1.1	V
UVLO circuit block						
UVLO lock release voltage	V _{UVLO}		7.0	7.4	7.8	V
UVLO hysteresis	V _{UVLO} _H			0.6		V
Error amplifier						
Input bias current	I _{EA} _IN				100	μА
Error amplifier transconductance	GEA		1000	1400	1800	μΑΛ
Common mode input voltage range	V _{EA} _R	V _{IN} =8 to 42V	0.0		1.6	V
Sink output current	I _{EA_} OSK	FB=1.0V		-100		μА
Source output current	I _{EA_} OSC	FB=0V		100		μА
Current detection amplifier gain	GISNS			1.3		
Over current limiter circuit block					1	
Reference current	ILIM		-10%	20	+10%	μА
Over current detection comparator offset voltage	V _{LIM} _OFS		-5		+5	mV
Over current detection comparator common	LIIVI—		V _{IN} -0.45		V _{IN}	V
mode input range						
PWM comparator						
Input threshold voltage	Vtmax	Duty cycle=DMAX	0.95	1.1	1.25	V
	Vt0	Duty cycle=0%	0.35	0.45	0.55	V
Maximum ON duty	DMAX		75	80		%
Output block						
Output stage ON resistance(the upper side)	R _{ON} H			5		Ω
Output stage ON resistance(the under side)	R _{ON} L			5		Ω
Output stage ON current(the upper side)	I _{ON} H		240			mA
Output stage ON current(the under side)	I _{ON} L		240			mA
The whole device					I	
Standby current	I _{CC} S	EN < 1V			60	μА
•		EN > 5V	+	3.6		

Pin Assignment



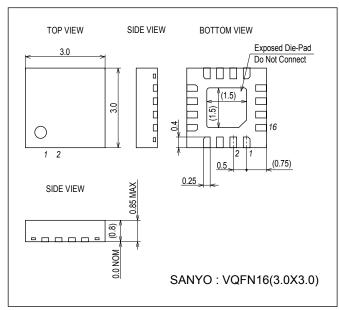
Pin Function

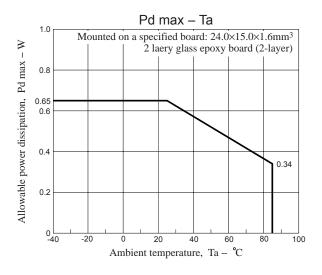
Pin No.	Pin name	Function		
1	COMP	Error amplifier output pin.		
		Connect a phase compensation circuit between this pin and GND.		
2	EN	ON/OFF pin.		
3	SW	Pin to connect with switching node. The source of Nch MOSFET connects to this pin.		
4	CBOOT	Bootstrap capacity connection pin. This pin becomes a GATE drive power supply of an external Nch MOSFET.		
		Connect a bypath capacitor between CBOOT and SW.		
5	HDRV	An external the upper MOSFET gate drive pin.		
6, 7	NC	No connection		
14, 15				
8	LDRV	An external the lower MOSFET gate drive pin.		
9	V_{DD}	Power supply pin for an external the MOS-FET gate drive.		
10	GND	Ground pin. Each reference voltage is based on the voltage of the ground pin.		
11	V _{IN}	Power supply pin.		
		This pin is monitored by UVLO function. When the voltage of this pin becomes 7.8V or more by UVLO function, The IC		
		starts and the soft start function operates.		
12	ILIM	Reference current pin for current detection.		
		The sink current of about 20 μ A flows to this pin. When a resistance is connected between this pin and V_{IN} outside and		
		the voltage applied to the SW pin is lower than the voltage of the terminal side of the resistance, the upper Nch MOSFET		
		is off by operating the current limiter comparator. This operation is reset with respect to each PWN pulse.		
13	SS/HICCUP	Pin to connect a capacitor for soft start. A capacitor for soft start is charged by using the voltage of about 4.3µA.		
		This pin ends the soft start period by using the voltage of about 0.9V and the frequency fold back function becomes		
		active.		
16	FB	Error amplifier reverse input pin.		
		By operating the converter, the voltage of this pin becomes 0.7V.		
		The voltage in which the output voltage is divided by an external resistance is applied to this pin.		
		Also, the oscillation frequency become one-eighth when the voltage of this pin becomes 0.4V or less after soft start		
		function.		

Package Dimensions

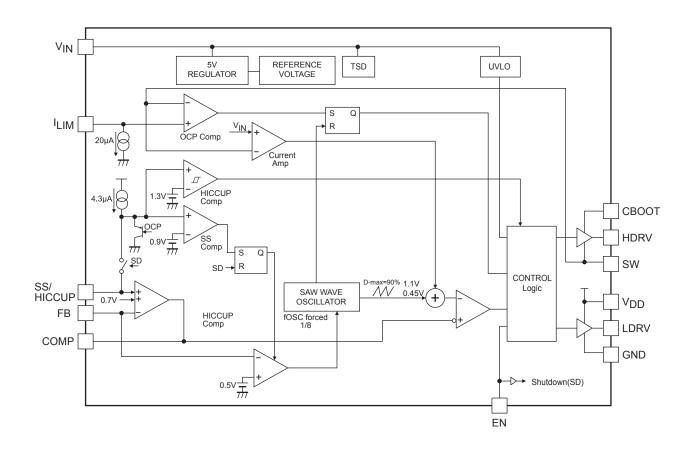
unit: mm (typ)

3394

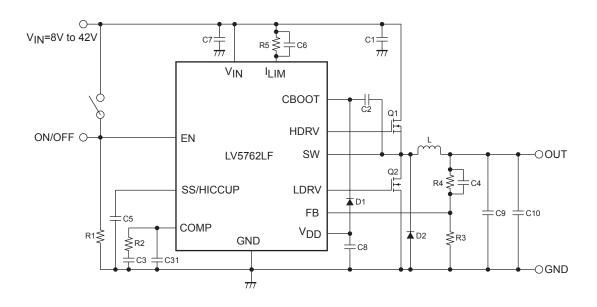




Block Diagram



Sample Application Circuit



- SANYO Semiconductor Co.,Ltd. assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all SANYO Semiconductor Co.,Ltd. products described or contained herein.
- SANYO Semiconductor Co.,Ltd. strives to supply high-quality high-reliability products, however, any and all semiconductor products fail or malfunction with some probability. It is possible that these probabilistic failures or malfunction could give rise to accidents or events that could endanger human lives, trouble that could give rise to smoke or fire, or accidents that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.
- In the event that any or all SANYO Semiconductor Co.,Ltd. products described or contained herein are controlled under any of applicable local export control laws and regulations, such products may require the export license from the authorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written consent of SANYO Semiconductor Co.,Ltd.
- Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the SANYO Semiconductor Co.,Ltd. product that you intend to use.
- Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production.
- Upon using the technical information or products described herein, neither warranty nor license shall be granted with regard to intellectual property rights or any other rights of SANYO Semiconductor Co.,Ltd. or any third party. SANYO Semiconductor Co.,Ltd. shall not be liable for any claim or suits with regard to a third party's intellectual property rights which has resulted from the use of the technical information and products mentioned above.

This catalog provides information as of June, 2010. Specifications and information herein are subject to change without notice.